

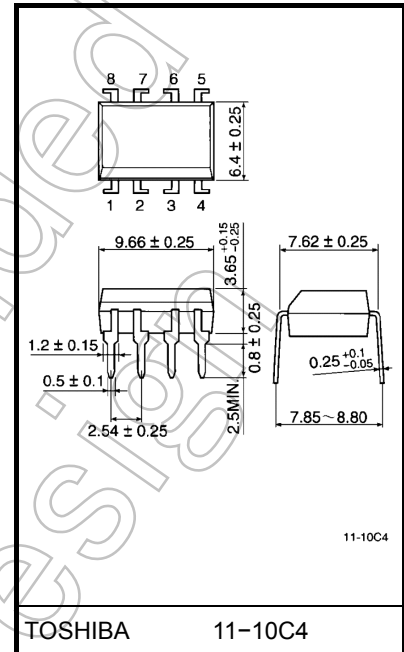
6N138, 6N139

Current Loop Driver
 Low Input Current Line Receiver
 CMOS Logic Interface

The TOSHIBA 6N138 and 6N139 consists of a GaAlAs infrared emitting diode coupled with a split-Darlington output configuration. A high speed GaAlAs Ired manufactured with an unique LPE junction, has the virtue of fast rise and fall time at low drive current.

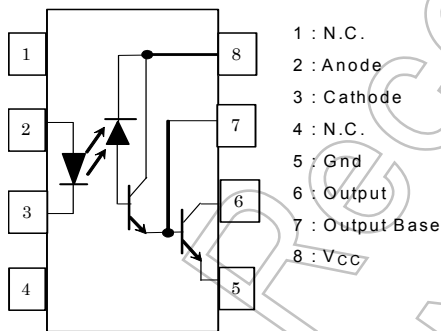
- Isolation voltage: 2500 Vrms (min)
- Current transfer ratio
 - : 6N138 - 300% (min) ($I_F=1.6\text{mA}$)
 - : 6N139 - 400% (min) ($I_F=0.5\text{mA}$)
- Switching time: 6N138 - $t_{PHL} = 10\mu\text{s}$ (max)
 - $t_{PLH} = 35\mu\text{s}$ (max)
 6N139 - $t_{PHL} = 1\mu\text{s}$ (max)
 - $t_{PLH} = 7\mu\text{s}$ (max)
- UL recognized: UL1577, file no. E67349

Unit: mm

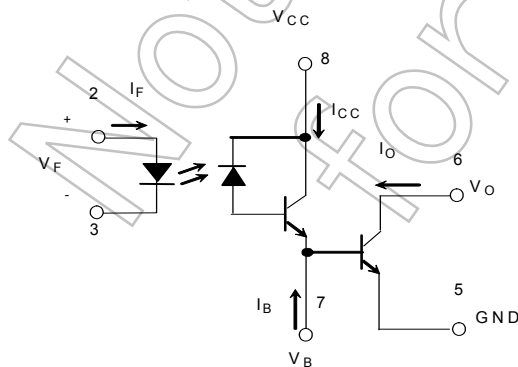


Weight: 0.54 g (typ.)

Pin Configuration (top view)



Schematic



Start of commercial production
 1988/02

Absolute Maximum Ratings (*) (Ta = 0°C to + 70°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current (Note 1)	I_F	20	mA
	Pulse forward current	$I_{FP}^{(*)}$	40	mA
	Total pulse forward current	$I_{FP}^{(**)}$	1	A
	Reverse voltage	V_R	5	V
	Diode power dissipation (Note 2)	P_D	35	mW
Detector	Output current (Note 3)	I_O	60	mA
	Emitter-base reverse voltage	V_{EB}	0.5	V
	Supply voltage	$V_{CC}^{(**)}$	-0.5 to 18	V
	Output voltage	$V_O^{(**)}$	-0.5 to 18	V
	Output power dissipation (Note 4)	P_O	100	mW
Operating temperature range		T_{opr}	0 to 70	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Lead solder temperature (10s) ^(*)		T_{sol}	260	°C
Isolation voltage (1minute, R.H.≤ 60%)		$BV_S^{(**)}$	2500	V_{rms}
			3540	V_{dc}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

(*) JEDEC registered data

(**) Not registered JEDEC

(*1) 50% duty cycle, 1ms pulse width

(*2) Pulse width 1μs, 300pps

(*3) 6N138... -0.5 to 7V

(*4) 1.6mm below seating plane

Electrical Characteristics
Over Recommended Temperature ($T_a = 0^\circ\text{C}$ to 70°C , unless otherwise noted)

Characteristic		Symbol	Test Condition	Min	(*5)Typ.	Max	Unit
Current transfer ratio (Note 5, 6)	6N139	CTR(*)	$I_F=0.5\text{mA}$, $V_O=0.4\text{V}$ $V_{CC}=4.5\text{V}$	400	800	—	%
	6N138		$I_F=1.6\text{mA}$, $V_O=0.4\text{V}$ $V_{CC}=4.5\text{V}$	500 300	900 600	—	
Logic low output voltage (Note 6)	6N139	V_{OL}	$I_F=1.6\text{mA}$, $I_O=6.4\text{mA}$ $V_{CC}=4.5\text{V}$	—	0.1	0.4	V
			$I_F=5\text{mA}$, $I_O=15\text{mA}$ $V_{CC}=4.5\text{V}$	—	0.1	0.4	
	$I_F=12\text{mA}$, $I_O=24\text{mA}$ $V_{CC}=4.5\text{V}$		—	0.2	0.4		
	6N138		$I_F=1.6\text{mA}$, $I_O=4.8\text{mA}$ $V_{CC}=4.5\text{V}$	—	0.1	0.4	
Logic high output current (Note 6)	6N139	I_{OH}^*	$I_F=0\text{mA}$, $V_O=V_{CC}=18\text{V}$	—	0.05	100	μA
	6N138		$I_F=0\text{mA}$, $V_O=V_{CC}=7\text{V}$	—	0.05	250	
Logic low supply current (Note 6)		I_{CCL}	$I_F=1.6\text{mA}$, $V_O=\text{Open}$ $V_{CC}=5\text{V}$	—	0.2	—	mA
Logic high supply current (Note 6)		I_{CCH}	$I_F=0\text{mA}$, $V_O=\text{Open}$, $V_{CC}=5\text{V}$	—	10	—	nA
Input forward voltage		V_F^*	$I_F=1.6\text{mA}$, $T_a=25^\circ\text{C}$	—	1.65	1.7	V
Input reverse breakdown voltage		BV_R^*	$I_R=10\mu\text{A}$, $T_a=25^\circ\text{C}$	5	—	—	V
Temperature coefficient of forward voltage		$\Delta V_F / \Delta T_a$	$I_F=1.6\text{mA}$	—	-1.9	—	mV / $^\circ\text{C}$
Input capacitance		C_{IN}	$f=1\text{MHz}$, $V_F=0$	—	60	—	pF
Resistance (input-output)		R_{I-O}	$V_{I-O}=500\text{V}$ R.H. $\leq 60\%$ (Note 7),	—	10^{12}	—	Ω
Capacitance (input-output)		C_{I-O}	$f=1\text{MHz}$ (Note 7)	—	0.6	—	pF

(**) JEDEC registered data.

(*5) All typical values are at $T_a=25^\circ\text{C}$ and $V_{CC}=5\text{V}$, unless otherwise noted.

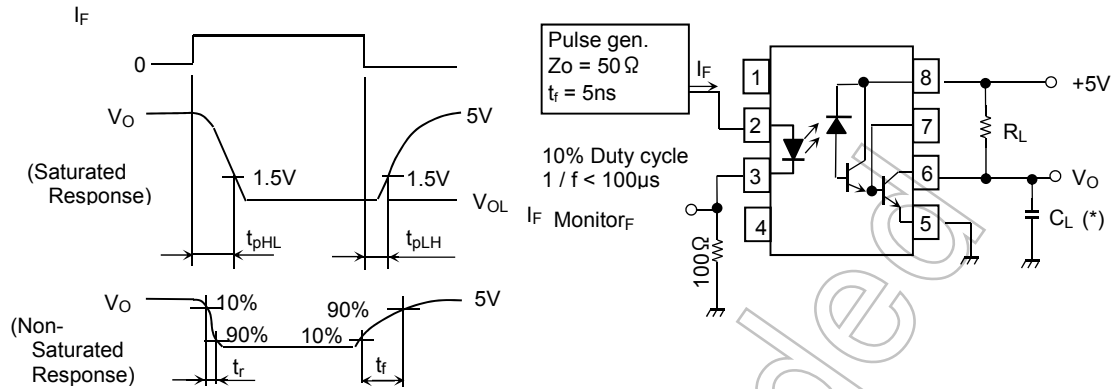
Switching Specifications (Ta=25°C, VCC=5V, unless otherwise specified)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Propagation delay time to logic low at output (Note 6, 8)	6N139	$t_{pHL}^{(*)}$	1	$I_F=0.5mA, R_L=4.7k\Omega$	—	5	25	μs
	6N138			$I_F=12mA, R_L=270\Omega$	—	0.2	1	
				$I_F=1.6mA, R_L=2.2k\Omega$	—	1	10	
Propagation delay time to logic high at output (Note 6, 8)	6N139	$t_{pLH}^{(*)}$	1	$I_F=0.5mA, R_L=4.7k\Omega$	—	5	60	μs
	6N138			$I_F=12mA, R_L=270\Omega$	—	1	7	
				$I_F=1.6mA, R_L=2.2k\Omega$	—	4	35	
Common mode transient immunity at logic high level output (Note 9)		CM_H	2	$I_F=0mA, R_L=2.2k\Omega$ $V_{CM}=400V_{p-p}$	—	500	—	$V / \mu s$
Common mode transient immunity at logic low level output (Note 9)		CM_L	2	$I_F=1.6mA$ $R_L=2.2k\Omega$ $V_{CM}=400V_{p-p}$	—	-500	—	$V / \mu s$

(*)JEDEC registered data.

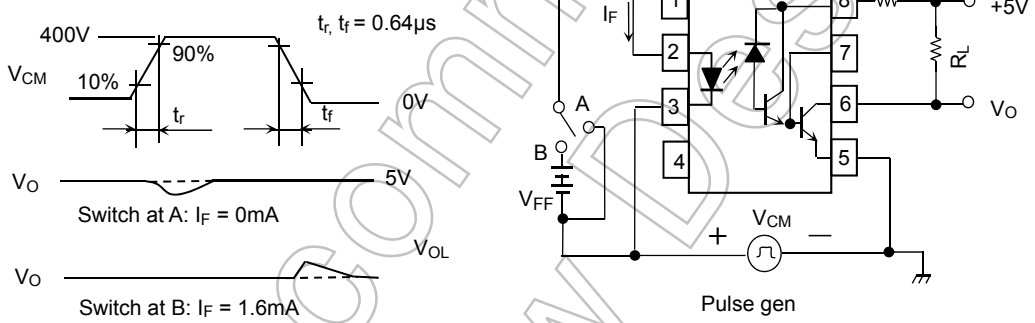
- (Note 1): Derate linearly above 50°C free-air temperature at a rate of 0.4mA / °C.
- (Note 2): Derate linearly above 50°C free-air temperature at a rate of 0.7mW / °C.
- (Note 3): Derate linearly above 25°C free-air temperature at a rate of 0.7mA / °C.
- (Note 4): Derate linearly above 25°C free-air temperature at a rate of 2.0mW / °C.
- (Note 5): DC CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I_O , to the forward LED input current, I_F , times 100%.
- (Note 6): Pin 7 open.
- (Note 7): Device considered a two-terminal device: Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.
- (Note 8): Use of a resistor between pin 5 and 7 will decrease gain and delay time.
- (Note 9): Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{CM} / dt on the leading edge of the common mode pulse, V_{CM} , to assure that the output will remain in a logic high state (i.e. $V_O > 2.0V$).
Common mode transient immunity in Logic Low level is the maximum tolerable (negative) dV_{CM} / dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e. $V_O < 0.8V$).

Test Circuit 1.



(*) C_L is approximately 15pF which includes probe and stray wiring capacitance.

Test Circuit 2.



Not Recommended for New Design

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